





Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			100	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous	T _C = 25 °C		20		
I _D	-Continuous	T _A = 25 °C	(Note 1a)	7	A	
	-Pulsed		(Note 4)	60		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	72	mJ	
D	Power Dissipation $T_{\rm C} = 25 ^{\circ}{\rm C}$			41	w	
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	V	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

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Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a	53	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Package Reel Size Tape Width		Quantity
FDMC86102	FDMC86102	Power 33	13"	12 mm	3000 units

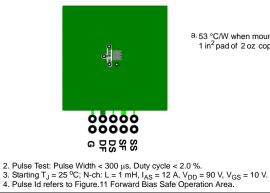
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FDMC86102 N
N-Channel S
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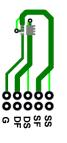
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, V_{GS} = 0 \ V$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		69		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \ \mu A$	2.0	3.1	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-9		mV/°C
-		V _{GS} = 10 V, I _D = 7 A		19.4	24	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 6 V, I_{D} = 5 A$		26.8	38	mΩ
		$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 7 \text{ A}, \text{T}_{J} = 125 ^{\circ}\text{C}$		32.8	41	
9 _{FS}	Forward Transconductance	$V_{DD} = 10 \text{ V}, \ \text{I}_{D} = 7 \text{ A}$		19		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance			725	965	pF
C _{oss}	Output Capacitance	──V _{DS} = 50 V, V _{GS} = 0 V, ──f = 1 MHz		175	235	pF
C _{rss}	Reverse Transfer Capacitance			15	25	pF
R _g	Gate Resistance			0.5		Ω
Switchin	g Characteristics					
t _{d(on)}	Turn-On Delay Time			8	17	ns
t _r	Rise Time	V _{DD} = 50 V, I _D = 7 A,		4	10	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_{GEN} = 6 Ω		14	25	ns
t _f	Fall Time			4	10	ns
0	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		13	18	nC
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 50 V$		8	11	nC
Q _{gs}	Total Gate Charge	I _D = 7 A		3.7		nC
Q _{gd}	Gate to Drain "Miller" Charge			3.6		nC
Drain-So	urce Diode Characteristics					
V		$V_{GS} = 0 V, I_S = 7 A$ (Note 2)		0.81	1.3	V
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, \text{ I}_{S} = 2 \text{ A} \qquad (\text{Note 2})$		0.75	1.2	V
t _{rr}	Reverse Recovery Time	— I _F = 7 A, di/dt = 100 A/μs		44	70	ns
Q _{rr}	Reverse Recovery Charge	$r_F = r R$, uvut = 100 A/µs	-	40	65	nC

Q_{rr} NOTES:

1. R_{0JA} is determined with the device mounted on a 1in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



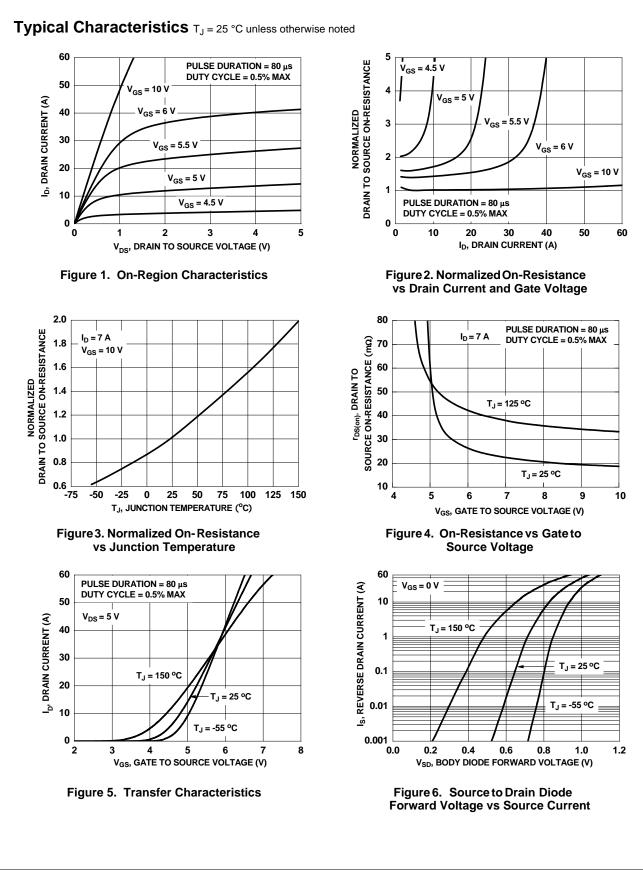
a.53 °C/W when mounted on a 1 in² pad of 2 oz copper



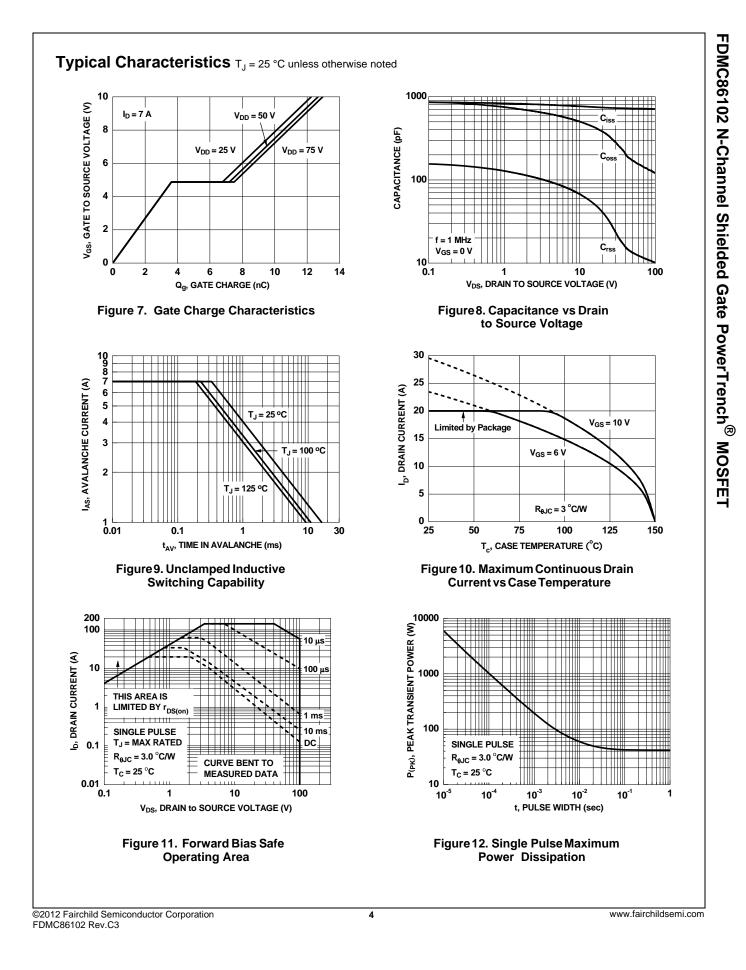
b. 125 °C/W when mounted on a minimum pad of 2 oz copper

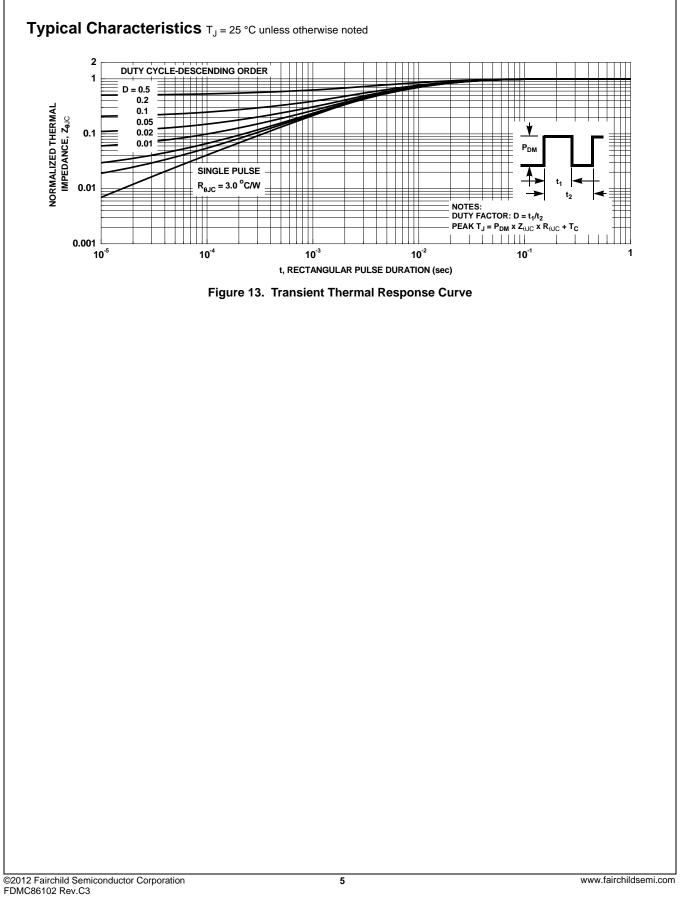
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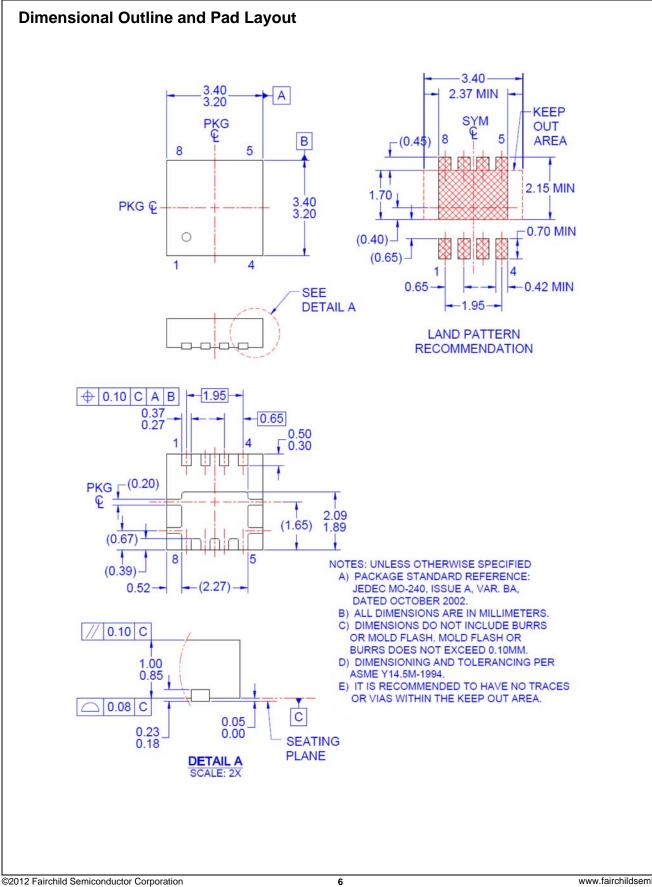


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FDMC86102 N-Channel Shielded Gate PowerTrench[®] MOSFET



FDMC86102 Rev.C3

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